

2STN2540-A

Low voltage fast-switching PNP power bipolar transistor

Features

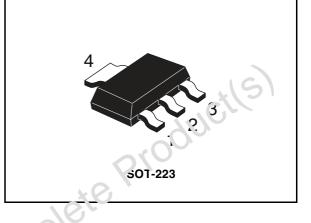
- The device is qualified for automotive application
- Very low collector-emitter saturation voltage
- High current gain characteristic
- Fast switching speed
- Surface mounting device in medium power SOT-223 package

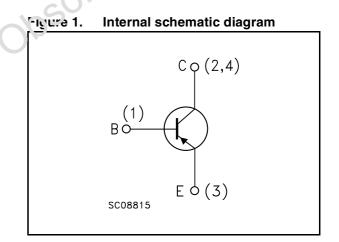
Applications

- Emergency lighting
- LED
- CCFL drivers (back lighting)
- Voltage regulation
- Relay driver

Description

The device in a PNP transistor manufactured using new "PB-HCP" (Fower Bipolar High Current Density) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.





Order code	Marking	Package	Packaging	
2STN2540-A	N2540	SOT-223	Tape & reel	

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Electrical ratings 1

Table 2.	Absolute maximum rating
	Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-40	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	-40	V
V_{EBO}	Emitter-base voltage (I _C = 0)	-6	V
Ι _C	Collector current	-5	Α
I _{CM}	Collector peak current (t _P < 5ms)	-10	A
I _{BM}	Base peak current (t _P < 5ms)	-2 C	Α
P _{tot}	Total dissipation at T _{amb} = 25°C	Ö.ö	W
T _{stg}	Storage temperature	-65 to 150	°C
ТJ	Max. operating junction temperature	150	°C
Table 3.	Thermal data		

Thermal data Table 3.

Symbol	Paramet	03	Value	Unit
$R_{thj-amb}^{(1)}$	Thermal resistance junction-amb	max	78	°C/W

obsolete Product 1. Device mounted on PCB are a of ton 2



Electrical characteristics 2

(T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E =0)	V _{CB} = -30 V			-0.1	μA
I _{EBO}	Emitter cut-off current (I _C =0)	V _{EB} = -5 V			-0.1	μA
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage		mA) mA	-80 -121 -140 -350	-1.20 180 -200 -450	nıV mV mV mV
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = -5 A I _B = -50	C mA		-1.3	v
V _{BE(on)} ⁽¹⁾	Base-emitter on voltage	V _{CE} = -2 V I _C 2 A			-1.25	V
h _{FE} ⁽¹⁾	DC current gain		2 V 200 2 V 150			
C _{CBO}	Collector-5แรว capacita.าเว	$I_E = 0$ $V_{CB} = -1$ f = 1MHz	10 V	80		pF
t _{cn} t _s t _f	Resistive load Turn-on time Storage time Fall time	$I_{C} = -1 A$ $V_{CC} = -1$ $-I_{B1} = I_{B2} = -0.1 A$ $T_{p} = 30 \ \mu A$	0 V	75 426 62		ns ns ns

Table 4. **Electrical characteristics**



2.1 Electrical characteristics (curves)

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Figure 2. Output characteristics
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Figure 3. DC current gain

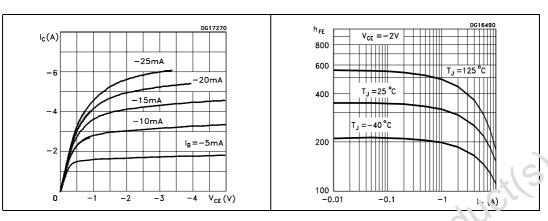
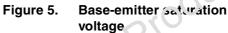
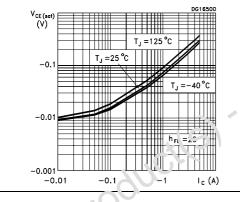


Figure 4. Collector-emitter saturation voltage





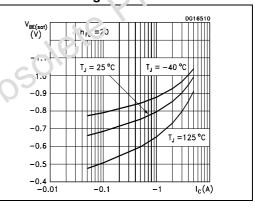
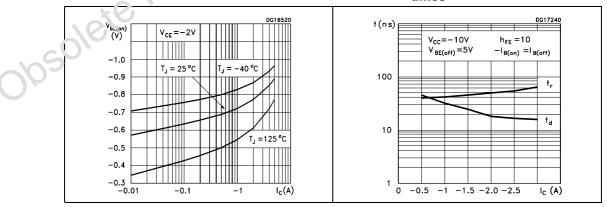


Figure 6. Bils ?-emitter on voltage

Figure 7. Resistive load switching times



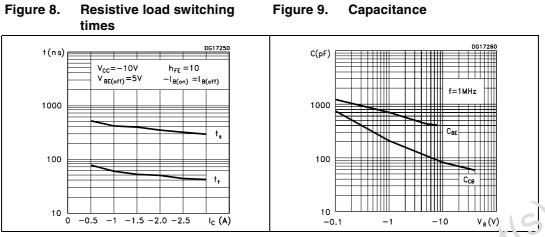
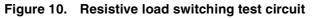
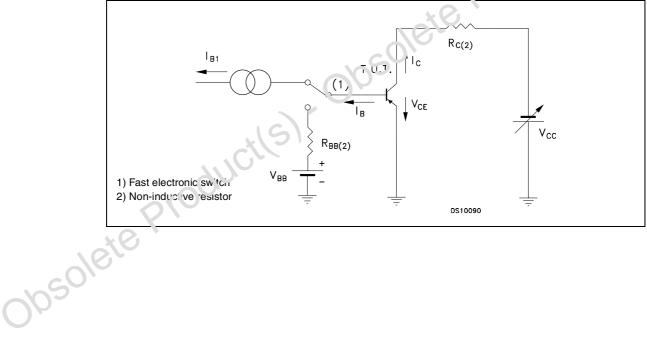


Figure 8. **Resistive load switching**

2.2 **Test circuit**





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3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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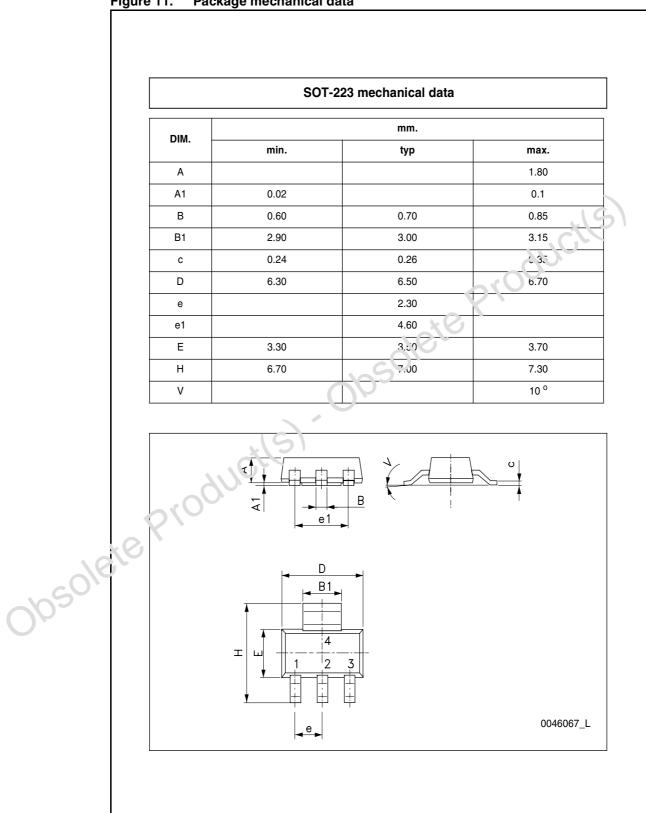


Figure 11. Package mechanical data



4 Revision history

Table 5. Document revision history

	Date	Revision	Changes
	23-Oct-2007	1	Initial release
	15-Jan-2008	2	Updated max package dimensions in lines "B" and "c" of the package mechanical data, <i>Figure 11</i> .
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